

### PECL DIGITAL VIDEO CLOCK SOURCE

ICS664-02

## **Description**

The ICS664-02 provides clock generation and conversion for clock rates commonly needed in HDTV digital video equipment. The ICS664-02 uses the latest Phase-Locked Loop (PLL) technology to provide excellent phase noise and long-term jitter performance for superior synchronization and S/N ratio.

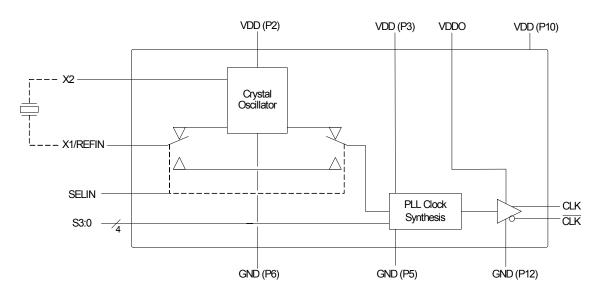
For audio sampling clocks generated from 27 MHz, use the ICS661.

Please contact IDT if you have a requirement for an input and output frequency not included in this document. IDT can rapidly modify this product to meet special requirements.

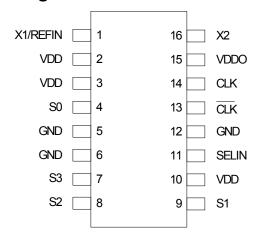
#### **Features**

- Packaged in 16-pin TSSOP
- Pb (lead) free package, RoHS compliant
- · Clock or crystal input
- · Low phase noise
- · Low jitter
- Exact (0 ppm) multiplication ratios
- Power-down control
- Improved phase noise over ICS660
- Differential outputs
- Supports SMTE 292M HD-SDI standard for HDTV broadcast

### **Block Diagram**



# **Pin Assignment**



16-pin 4.40 mil body, 0.65 mm pitch TSSOP

# **Output Clock Selection Table**

S3	S2	S1	S0	Input Frequency (MHz)	Output Frequency (MHz)
0	0	0	0		Power down
0	0	0	1	Pass thru	Input Freq
0	0	1	0	27	74.25
0	0	1	1	27	74.175824
0	1	0	0	13.5	74.25
0	1	0	1	13.5	74.175824
0	1	1	0	RESERVED	RESERVED
0	1	1	1	RESERVED	RESERVED
1	0	0	0	74.25	54
1	0	0	1	74.175824	54
1	0	1	0	RESERVED	RESERVED
1	0	1	1	RESERVED	RESERVED
1	1	0	0	54	74.25
1	1	0	1	54	74.175824
1	1	1	0	54	13.5
1	1	1	1	27	13.5

# **Pin Descriptions**

Pin Number	Pin Name	Pin Type	Pin Description
1	X1/REFIN	Input	Connect this pin to a crystal or clock input
2	VDD	Power	Power supply for crystal oscillator.
3	VDD	Power	Power supply for PLL.
4	S0	Input	Output frequency selection. Determines output frequency per table above. On chip pull-up.
5	GND	Power	Ground for PLL.
6	GND	Power	Ground for oscillator.
7	S3	Input	Output frequency selection. Determines output frequency per table above. On chip pull-up.
8	S2	Input	Output frequency selection. Determines output frequency per table above. On chip pull-up.
9	S1	Input	Output frequency selection. Determines output frequency per table above. On chip pull-up.
10	VDD	Power	Power supply.
11	SELIN	Input	Low for clock input, high for crystal. On chip pull-up.
12	GND	Power	Ground for output stage
13	CLK	Output	Complimentary clock output.
14	CLK	Output	Clock output.
15	VDDO	Power	Power supply for output stage.
16	X2	Input	Connect this pin to a crystal. Leave open if using a clock input.

### **Application Information**

#### **Termination Resistor**

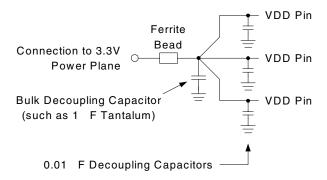
Terminate the outputs with  $50\Omega$  to ground.

#### **Decoupling Capacitors**

As with any high-performance mixed-signal IC, the ICS664-02 must be isolated from system power supply noise to perform optimally.

Decoupling capacitors of 0.01µF must be connected between each VDD and the PCB ground plane. To further guard against interfering system supply noise, the ICS664-02 should use one common connection to the PCB power plane as shown in the diagram on the next page. The ferrite bead and bulk capacitor help reduce lower frequency noise in the supply that can lead to output clock phase modulation.

### **Recommended Power Supply Connection for Optimal Device Performance**



All power supply pins must be connected to the same voltage, except VDDO, which may be connected to a lower voltage in order to change the output level.

To achieve the absolute minimum jitter, power the part with a dedicated LDO regulator, which will provide high isolation from power supply noise. Many companies produce very small, inexpensive regulators; an example is the National Semiconductor LP2985.

#### **Crystal Load Capacitors**

If a crystal is used, the device crystal connections should include pads for capacitors from X1 to ground and from X2 to ground. These capacitors are used to adjust the stray capacitance of the board to match the nominally required crystal load capacitance. To reduce possible noise pickup, use very short PCB traces (and no vias) been the crystal and device.

The value of the load capacitors can be roughly determined by the formula  $C = 2(C_1 - 6)$  where C is the load capacitor connected to X1 and X2, and C1 is the specified value of the load capacitance for the crystal. A typical crystal C<sub>1</sub> is 18 pF, so C = 2(18 - 6) = 24 pF. Because these capacitors adjust the stray capacitance of the PCB, check the output frequency using your final layout to see if the value of C should be changed.

#### **PCB Layout Recommendations**

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

- 1) Each 0.01µF decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between decoupling capacitor and VDD pin. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via. Distance of the ferrite bead and bulk decoupling from the device is less critical.
- 2) The external crystal should be mounted next to the device with short traces. The X1 and X2 traces should not be routed next to each other with minimum spaces, instead they should be separated and away from other traces.
- 3) To minimize EMI, and obtain the best signal integrity, the  $50\Omega$  series termination resistor should be placed close to the clock output.
- 4) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers (the ferrite bead and bulk decoupling capacitor can be mounted on the back). Other signal traces should be routed away from the ICS664-02. This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

## **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the ICS664-02. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating		
Supply Voltage, VDD	5.5 V		
All Inputs and Outputs	-0.5V to VDD+0.5 V		
Ambient Operating Temperature	0 to +70° C		
Storage Temperature	-65 to +150° C		
Junction Temperature	125° C		
Soldering Temperature	260° C		

## **Recommended Operation Conditions**

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature	0		+70	°C
Power Supply Voltage (measured in respect to GND)	+3.0		+3.6	V

### **DC Electrical Characteristics**

Unless stated otherwise, **VDD = 3.3 V ±10%**, Ambient Temperature 0 to +70° C

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
	VDD		3.0		3.6	V
Operating Voltage	VDDO		2.5		VDD	V
Supply Current	IDD	No Load		25		mA
Standby Supply Current	IDDPD			75		μΑ
Input High Voltage	V <sub>IH</sub>		2			V
Input Low Voltage	V <sub>IL</sub>				0.8	V
Output High Voltage	V <sub>OH</sub>		VDDO-1.5		VDDO-1.1	V
Output Low Voltage	V <sub>OL</sub>		VDDO-2.0		VDDO-1.8	V
Input Capacitance	C <sub>IN</sub>	input pins		7		pF
Internal Pull-up Resistor	R <sub>PU</sub>			120		kΩ

## **AC Electrical Characteristics**

Unless stated otherwise, **VDD = 3.3 V ±10%**, Ambient Temperature 0 to +70° C

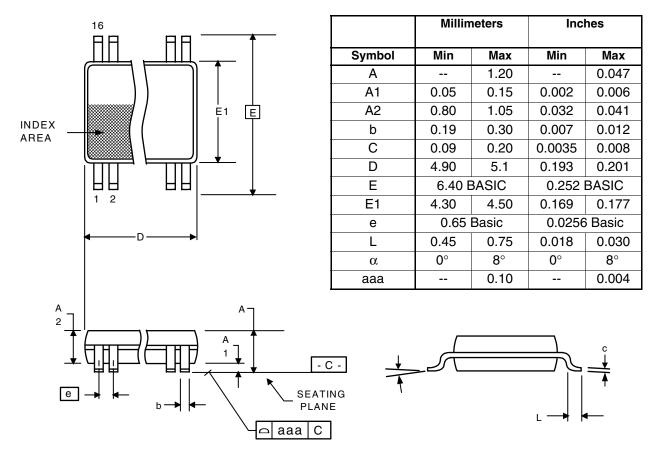
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Crystal Frequency					28	MHz
Output Clock Rise Time	t <sub>OR</sub>	20% to 80%, 15 pF load			1.5	ns
Output Clock Fall Time	t <sub>OF</sub>	80% to 20%, 15 pF load			1.5	ns
Output Duty Cycle	t <sub>OD</sub>	at VDD/2, 15 pF load	40	49 to 51	60	%
Power-up Time	t <sub>PU</sub>	Inputs out of PD state to clocks stable			10	ms
Power-down Time	t <sub>PD</sub>	Inputs in PD state to clocks off			1	μs
Jitter, Short term				70		ps p-p
Jitter, Long term		10 μs delay		300		ps p-p
Single Sideband Phase Noise		10 kHz offset		-120		dBc
Actual Mean Frequency Error versus Target				0		ppm

## **Thermal Characteristics**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{JA}$	Still air		78		° C/W
Ambient	$\theta_{JA}$	1 m/s air flow		70		° C/W
	$\theta_{JA}$	3 m/s air flow		68		° C/W
Thermal Resistance Junction to Case	$\theta_{JC}$			37		° C/W

### Package Outline and Package Dimensions (16-pin TSSOP, 4.40 mm Body, 0.65 mm Pitch)

Package dimensions are kept current with JEDEC Publication No. 95, MO-153



## **Ordering Information**

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
664G-02LF	664G02LF	Tubes	16-pin TSSOP	0 to +70° C
664G-02LFT	664G02LF	Tape and Reel	16-pin TSSOP	0 to +70° C

#### "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

While the information presented herein has been checked for both accuracy and reliability, Integrated Device Technology (IDT) assumes no responsibility for either its use or for the infringement of any patents or other rights of third parties, which would result from its use. No other circuits, patents, or licenses are implied. This product is intended for use in normal commercial applications. Any other applications such as those requiring extended temperature range, high reliability, or other extraordinary environmental requirements are not recommended without additional processing by IDT. IDT reserves the right to change any circuitry or specifications without notice. IDT does not authorize or warrant any IDT product for use in life support devices or critical medical instruments.

# Innovate with IDT and accelerate your future networks. Contact:

www.IDT.com

For Sales

800-345-7015 408-284-8200 Fax: 408-284-2775 For Tech Support

www.idt.com/go/clockhelp

#### **Corporate Headquarters**

Integrated Device Technology, Inc. www.idt.com

